2019 Workshop on Polarized Sources, Targets, and Polarimetry



Contribution ID: 67

Type: not specified

Improved robustness of GaAs-based photocathodes activated by Cs, Sb, and O2

Friday, 27 September 2019 14:20 (20 minutes)

GaAs-based photocathodes are widely used to produce highly spin polarized electron beams at high currents. Spin polarized photoelectrons can escape into vacuum only when GaAs surface is activated to Negative Electron Affinity (NEA). The NEA surface is notorious for extreme vacuum sensitivity, and this results in rapid QE degradation. We activated GaAs samples by unconventional methods using Cs, Sb, and oxygen. We present successful NEA activation on GaAs surface and more than a order of magnitude improvement in charge extraction slifetime compared to the standard Cs-O2 activation without significant loss in spin polarization.

Summary

Primary author:BAE, Jai Kwan (Cornell)Presenter:BAE, Jai Kwan (Cornell)Session Classification:Polarized Sources

Track Classification: Polarized Sources